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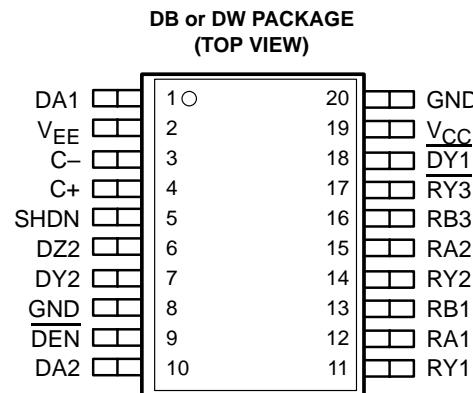
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SN75LBC776 SINGLE-CHIP GeoPort™ TRANSCEIVER

SLLS221B – NOVEMBER 1995 – REVISED MARCH 2002

- **Single-Chip Interface Solution for the 9-terminal GeoPort™ Host (DTE)**
- **Designed to Operate up to 4 Mbit/s Full Duplex**
- **Single 5-V Supply Operation**
- **6-kV ESD Protection on All Terminals**
- **Backward compatible With AppleTalk™ and LocalTalk™**
- **Combines Multiple Components into a Single-chip Solution**
- **Complements the SN75LBC777 9-Terminal GeoPort Peripheral (DCE) Interface Device**
- **LinBiCMOS™ Process Technology**



description

The SN75LBC776 is a low-power LinBiCMOS device that incorporates the drivers and receivers for a 9-pin GeoPort host interface. GeoPort combines hybrid EIA/TIA-422-B and EIA/TIA-423-B drivers and receivers to transmit data up to four megabits per second (Mbit/s) full duplex. GeoPort is a serial communications standard that is intended to replace the RS-232, Appletalk, and LocalTalk printer ports all in one connector in addition to providing real-time data transfer capability. It provides point-to-point connections between GeoPort-compatible devices with data transmission rates up to 4 Mbit/s full duplex and a hot-plug feature. Applications include connection to telephony, integrated services digital network (ISDN), digital sound and imaging, fax-data modems, and other serial and parallel connections. The GeoPort is backwardly compatible to both LocalTalk and AppleTalk.

While the SN75LBC776 is powered-off (V_{CC} = 0) the outputs are in a high-impedance state. When the shutdown (SHDN) terminal is high, the charge pump is powered down and the outputs are in a high-impedance state. The driver enable (DEN) terminal sends the outputs of the differential driver into a high-impedance state with a high input signal. All drivers and receivers have fail-safe mechanisms to ensure a high output state when the inputs are left open.

A switched-capacitor voltage converter generates the negative voltage required from a single 5-V supply using four 0.1- μ F capacitors, two capacitors between the C+ and C- terminals and two capacitors between V_{EE} and ground.

The SN75LBC776 is characterized for operation over the 0°C to 70°C temperature range.



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DRIVER FUNCTION TABLE[†]

Driver Function Table						
INPUT DA1	INPUT DA2	ENABLE SHDN	ENABLE DEN	OUTPUT DY1	OUTPUT DY2	OUTPUT DZ2
H	X	L	X	L	X	X
L	X	L	X	H	X	X
X	H	L	L	X	H	L
X	L	L	L	X	L	H
OPEN	OPEN	L	L	L	H	L
X	X	H	X	Z	Z	Z
X	X	X	H	X	Z	Z
X	X	OPEN	OPEN	Z	Z	Z

† H = high level L = low level X = irrelevant ? = indeterminate Z = high impedance (off)

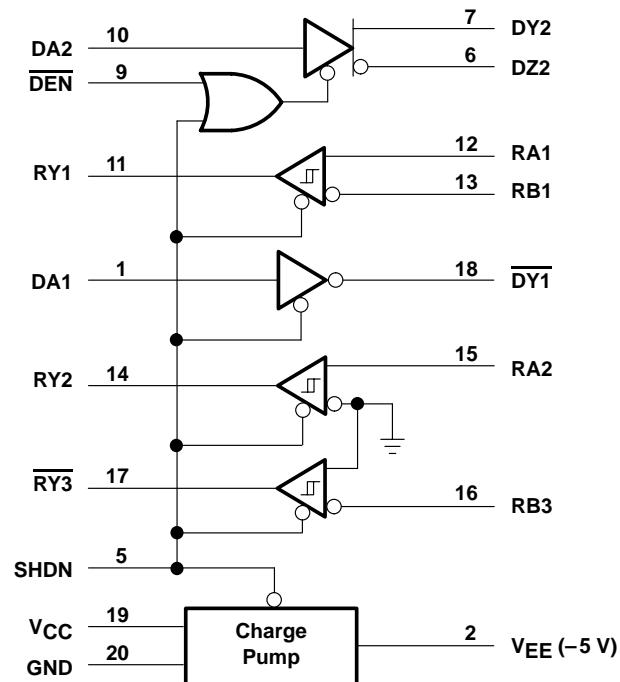
RECEIVER FUNCTION TABLET

INPUT RA1	INPUT RB1	INPUT RA2 & RB3	ENABLE SHDN	OUTPUT RY1	OUTPUT RY2	OUTPUT RY3
H	L	H	L	H	H	L
L	H	L	L	L	L	H
OPEN	OPEN		L	H	H	H
SHORT‡	SHORT‡		L	?	?	?
X	X	X	H	Z	Z	Z
X	X	X	OPEN	Z	Z	Z

† H = high level L = low level X = irrelevant ? = indeterminate Z = high impedance (off)

$\pm 0.2 \text{ V} < V_{ID} < 0.2 \text{ V}$

function logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to network ground terminal unless otherwise noted.
2. This parameter is measured in accordance with MIL-STD-883C, Method 2015.7.

DISSIPATION RATING TABLE

DISCUSSION RATING TABLE			
PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	OPERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING
DB	1035 mW	8.3 mW/ $^\circ\text{C}$	660 mW
DW	1125 mW	9.0 mW/ $^\circ\text{C}$	720 mW

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recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}		4.75	5	5.25	V
High-level input voltage, V_{IH}	DA, SHDN, \overline{DEN}	2		5.25	V
Low-level input voltage, V_{IL}	DA, SHDN, \overline{DEN}			0.8	V
Receiver common-mode input voltage, V_{IC}		-7		7	V
Receiver differential input voltage, V_{ID}		-12		12	V
Voltage-converter filter capacitance		0.2			μ F
Voltage-converter filter-capacitor equivalent series resistance (ESR)				0.2	Ω
Operating free-air temperature, T_A		0		70	°C

driver electrical characteristics over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OH} High-level output voltage	Single ended, See Figure 1	$R_L = 12 \text{ k}\Omega$	3.6	4.53	V
V_{OL} Low-level output voltage		$R_L = 120 \Omega$	2	3.63	V
$ V_{OD} $ Magnitude of differential output voltage $ V_{(DY)} - V_{(DZ)} $		$R_L = 12 \text{ k}\Omega$	-4.53	-3.6	V
$\Delta V_{OD} $ Change in differential voltage magnitude		$R_L = 120 \Omega$	-2.7	-1.8	V
V_{OC} Common-mode output voltage	See Figure 2	$R_L = 120 \Omega$, See Figure 2	4		V
$ \Delta V_{OC(SS)} $ Magnitude of change, common-mode steady state output voltage				250	mV
$ \Delta V_{OC(PP)} $ Magnitude of change, common-mode peak-to-peak output voltage				200	mV
I_{CC} Supply current	SHDN = $\overline{DEN} = 0 \text{ V}$, No load	7	15		mA
				100	μ A
I_{OZ} High-impedance output current	$V_O = -10 \text{ V to } 10 \text{ V}$, $V_{CC} = 0 \text{ or } 5 \text{ V}$			± 100	μ A
I_{OS} Short-circuit output current (see Note 3)	$V_O = -5 \text{ V to } 5 \text{ V}$		± 170	± 450	mA

NOTE 3: Not more than one output should be shorted at one time.

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driver switching characteristics over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PHL}	Propagation delay time, high-to-low level output	Single ended, See Figure 4	42	75	ns	
t _{PLH}	Propagation delay time, low-to-high level output		41	75	ns	
t _{PZL}	Driver output enable time to low-level output		25	100	μs	
t _{PZH}	Driver output enable time to high-level output		25	100	μs	
t _{PLZ}	Driver output disable time from low-level output		28	100	ns	
t _{PHZ}	Driver output disable time from high-level output		37	100	ns	
t _r	Rise time		10	25	75	ns
t _f	Fall time		10	23	75	ns
t _{PHL}	Propagation delay time, high-to-low level output		40	75	ns	
t _{PLH}	Propagation delay time, low-to-high level output		42	75	ns	
t _{PZL}	Driver output enable time to low-level output	Differential, See Figure 5	25	100	μs	
	SHDN		29	150	ns	
t _{PZH}	Driver output enable time to high-level output		25	100	μs	
	DEN		35	150	ns	
t _{PLZ}	Driver output disable time from low-level output		28	100	ns	
	SHDN		34	100	ns	
t _{PHZ}	Driver output disable time from high-level output		37	100	ns	
	SHDN		34	100	ns	
t _r	Rise time		10	27	75	ns
t _f	Fall time		10	26	75	ns
t _{SK(p)}	Pulse skew, t _{PLH} – t _{PHL}		22		ns	

receiver electrical characteristics over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IT+}	Positive-going input threshold voltage	See Figure 6			200	mV
V _{IT-}	Negative-going input threshold voltage				-200	
V _{hys}	Differential input voltage hysteresis (V _{IT+} – V _{IT-})				50	
V _{OH}	High-level output voltage (see Note 4)	V _{IC} = 0, I _{OH} = -2 mA, See Figure 6	2	4.9		V
V _{OL}	Low-level output voltage	V _{IC} = 0, I _{OL} = 2 mA, See Figure 6	0.2	0.8		V
I _{OS}	Short-circuit output current	V _O = 0	-85	-45		mA
		V _O = V _{CC}			47	
R _I	Input resistance	V _{CC} = 0 or 5.25 V, V _I = -12 V to 12 V	6	30		kΩ

NOTE 4: When the inputs are left unconnected, receivers one and two interpret these as high-level inputs and receiver three interprets these as low-level inputs so that all outputs are at a high level.

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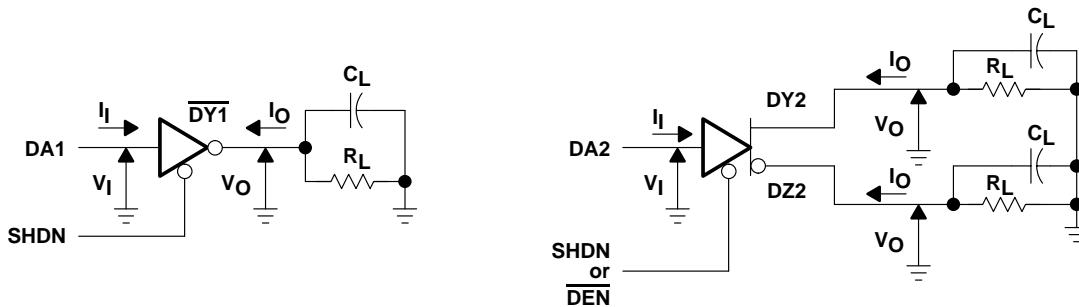
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receiver switching characteristics over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PHL} Propagation delay time, high-to-low-level output	R _L = 2 kΩ, See Figure 6	31	75	ns	
t _{PLH} Propagation delay time, low-to-high level output		30	75	ns	
t _r Rise time		15	30	ns	
t _f Fall time		15	30	ns	
t _{SK(P)} Pulse skew t _{PLH} –t _{PHL}		20	ns		
t _{PZL} Receiver output enable time to low level output	Differential, See Figure 7	35	100	ns	
t _{PZH} Receiver output enable time to high level output		32	100	ns	
t _{PLZ} Receiver output disable time from low level output		21	100	ns	
t _{PHZ} Receiver output disable time from high level output		21	100	ns	
t _{PZL} Receiver output enable time to low level output	Single ended, See Figure 7	12	25	μs	
t _{PZH} Receiver output enable time to high level output		12	25	μs	
t _{PLZ} Receiver output disable time from low level output		25	100	ns	
t _{PHZ} Receiver output disable time from high level output		125	400	ns	

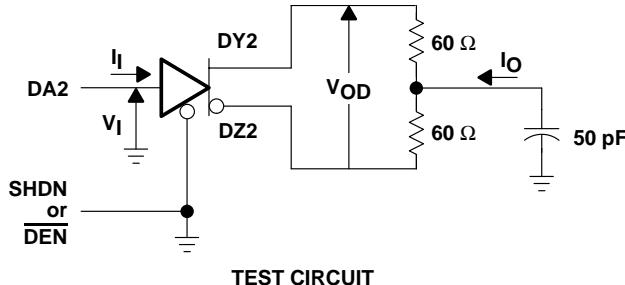
PARAMETER MEASUREMENT INFORMATION



NOTE A: $C_L = 50 \text{ pF}$

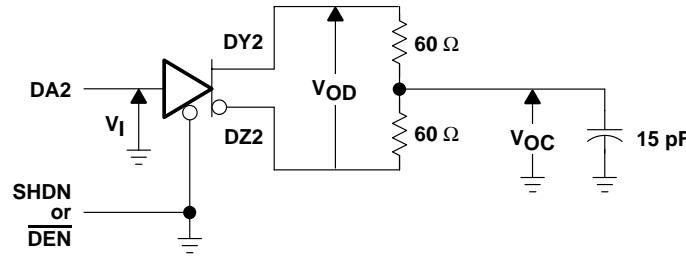
TEST CIRCUIT

Figure 1. Single-Ended Driver DC Parameter Test

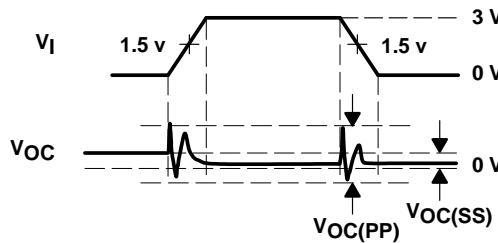


TEST CIRCUIT

Figure 2. Differential Driver DC Parameter Test



TEST CIRCUIT (see Note A)



VOLTAGE WAVEFORM

NOTE A: Measured 3dB bandwidth = 300 MHz

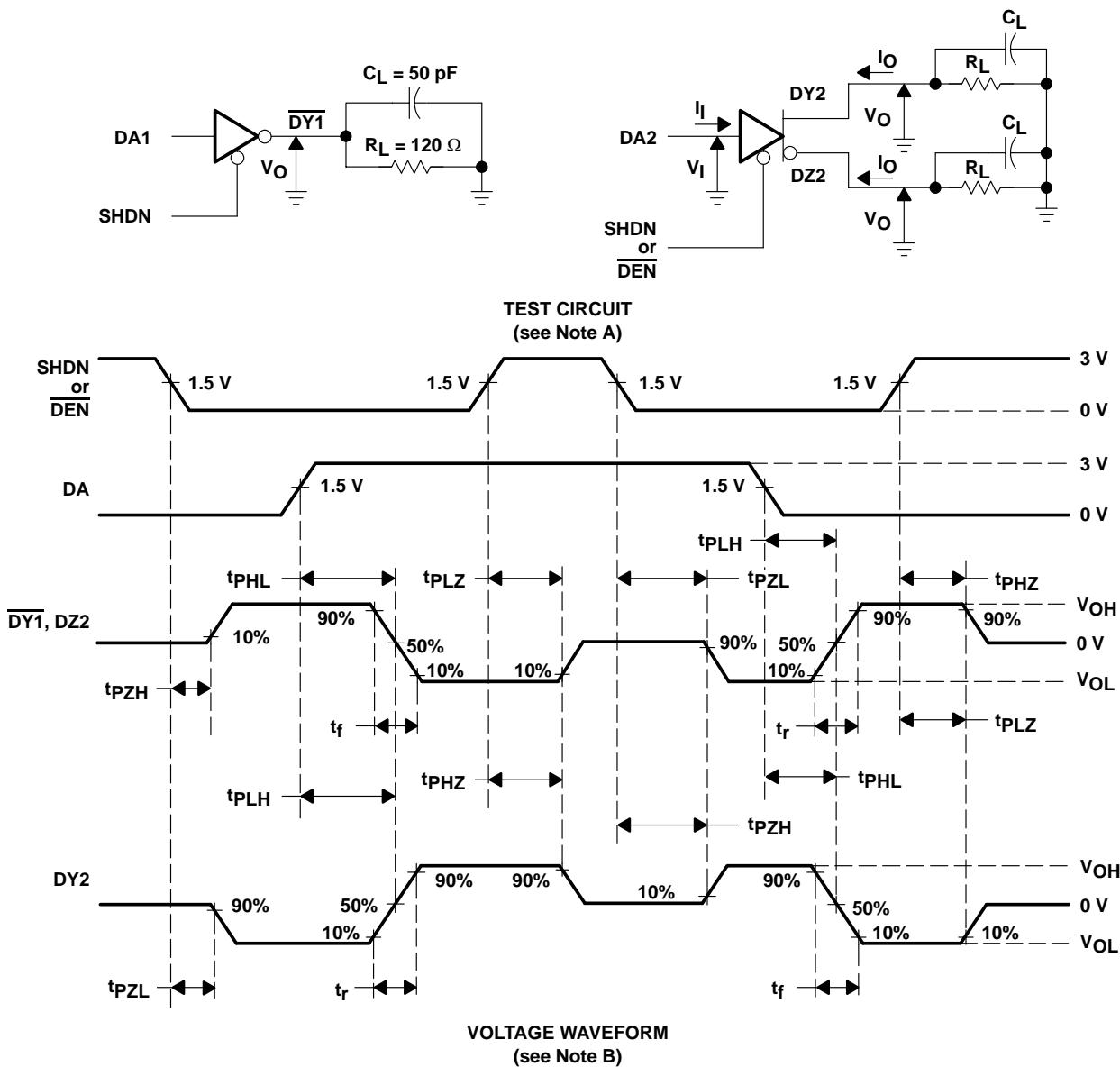
Figure 3. Differential-Driver Common-Mode Output Voltage Tests

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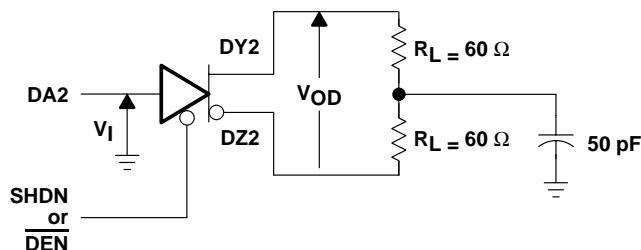
PARAMETER MEASUREMENT INFORMATION



NOTES: A. $C_L = 50 \text{ pF}$, $R_L = 120 \Omega$
B. The input waveform t_f , $t_f \leq 10 \text{ ns}$.

Figure 4. Single-Ended Driver Propagation and Transition Times

PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT

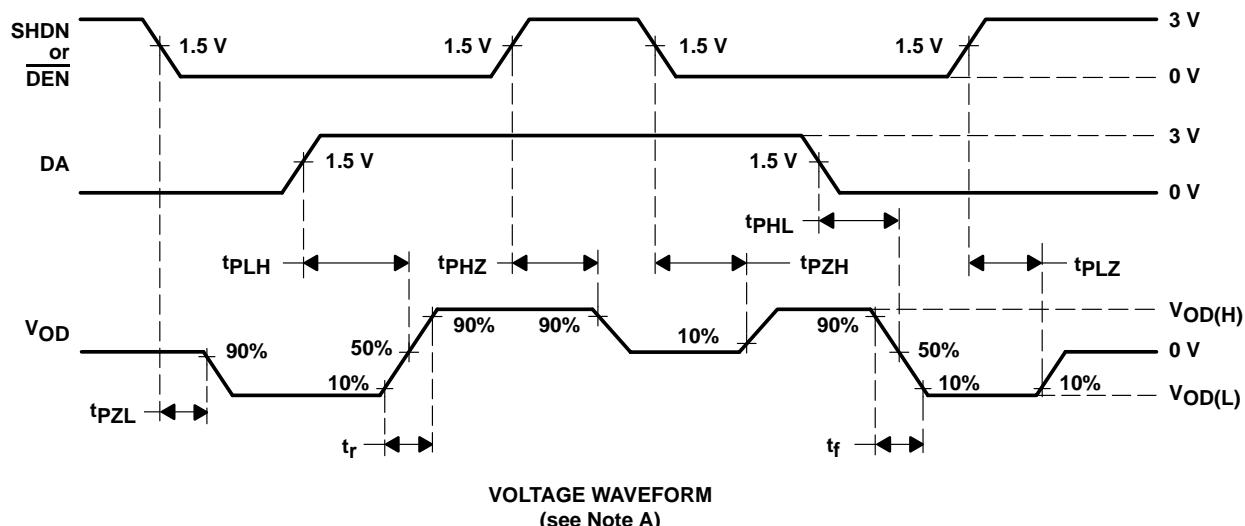
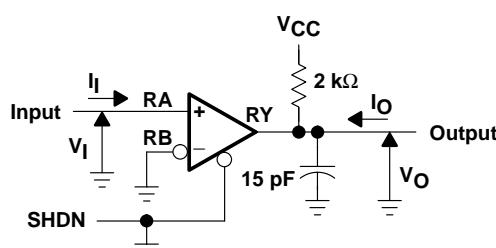


Figure 5. Differential Driver Propagation and Transition Times



TEST CIRCUIT

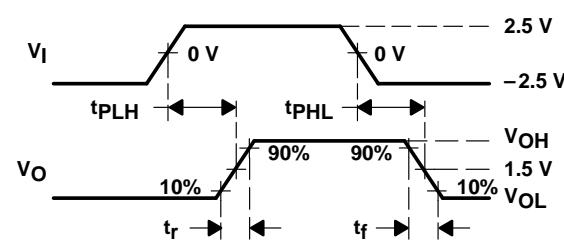


Figure 6. Receiver Propagation and Transition Times

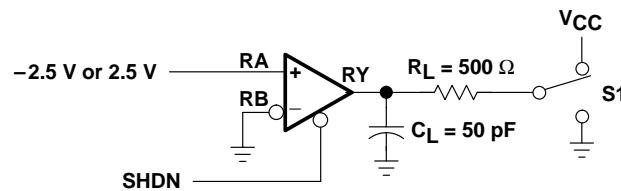
NOTE A: The input waveform $t_r, t_f \leq 10$ ns.

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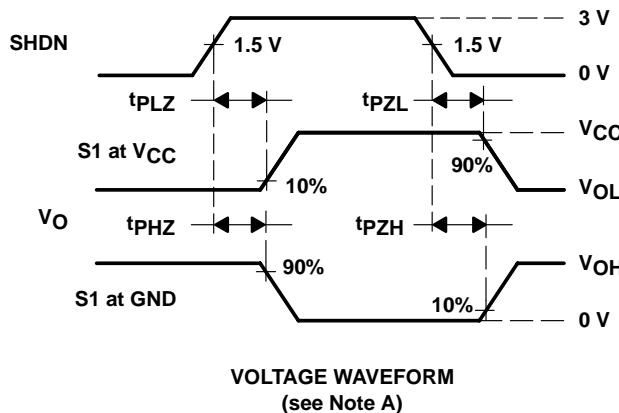
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PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT



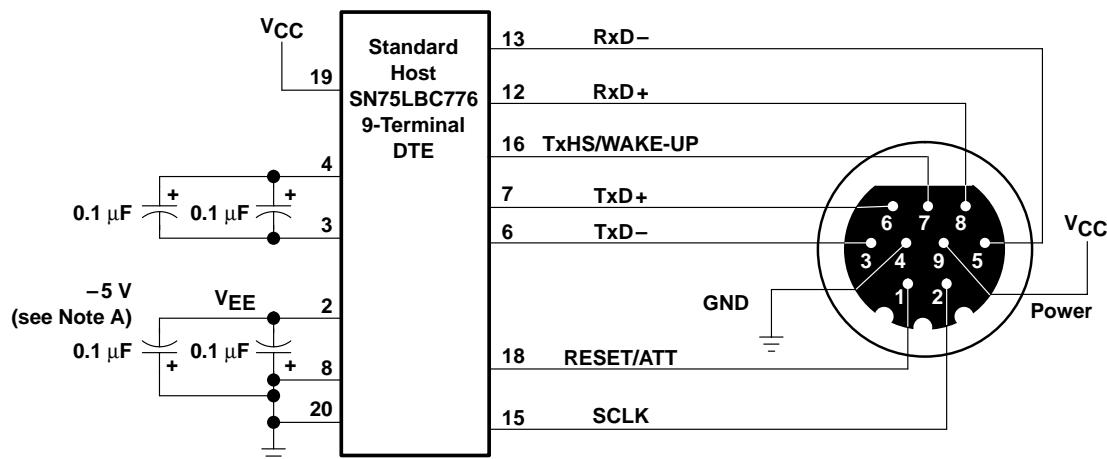
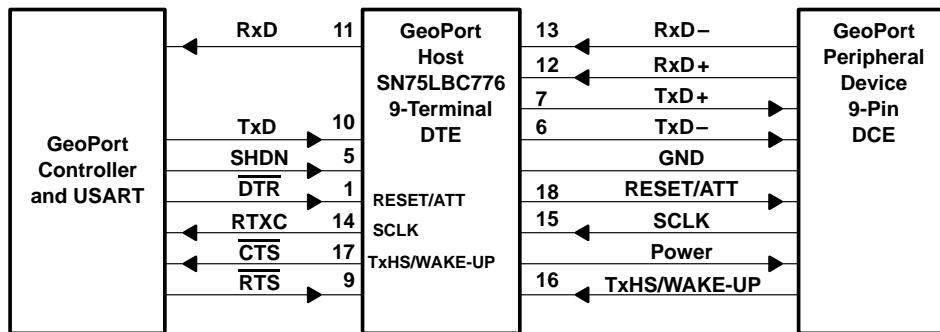
NOTE A: The input waveform $t_r, t_f \leq 10$ ns.

Figure 7. Receiver Enable and Disable Test Circuit and Waveforms

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APPLICATION INFORMATION



NOTE A: The AVX 0603YC104MATXA or equivalent is one of the possible capacitors that can be used as the charge pump capacitor.

Figure 8. GeoPort 9-Terminal DTE Connection Application

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APPLICATION INFORMATION

generator characteristics

PARAMETER	TEST CONDITIONS	EIA/TIA-232/V.28		EIA/TIA-423/V.10		562		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
V _O	Output voltage magnitude	Open circuit	25	4	6	13.2	V	
		3 kΩ ≤ R _L ≤ 7 kΩ	5	15	NA	3.7	V	
		R _L = 450 Ω	NA	3.6	NA	NA	V	
V _{O(RING)}	Output voltage ringing		NA		10%	5%		
I _{OS}	Short-circuit output current	V _O = 0	100	150	60	60	mA	
I _{O(OFF)}	Power-off output current	V _{CC} = 0, V _O < 2 V	300	NA	300	300	Ω	
		V _{CC} = 0, V _O < 6 V	NA	±100	NA	NA	μA	
SR	Output voltage slew rate		30	NA	4	30	V/μs	
t _t	Transition time	±3.3 V to ±3.3 V	NA	NA	0.22	2.1	μs	
		±3 V to ±3 V	0.04	NA	NA	NA	ui†	
		10% to 90%	NA	0.3	NA	NA	ui†	

† ui is the unit interval and is the inverse of the signaling rate (bit transmit time).

receiver characteristics

PARAMETER	TEST CONDITIONS	EIA/TIA-232/V.28		EIA/TIA-423/V.10		562		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
V _I	Input voltage magnitude		25		10	25	V	
V _{IT}	V _I < 15 V	-3	3	NA	NA	-3	3	V
	V _I < 10 V	NA	NA	-0.2	0.2	NA	NA	
R _I	3 V < V _I < 15 V	3	7	NA	NA	3	7	kΩ
	V _I < 10 V	NA	NA	4	NA	NA	NA	kΩ

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN75LBC776DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		75LB776	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

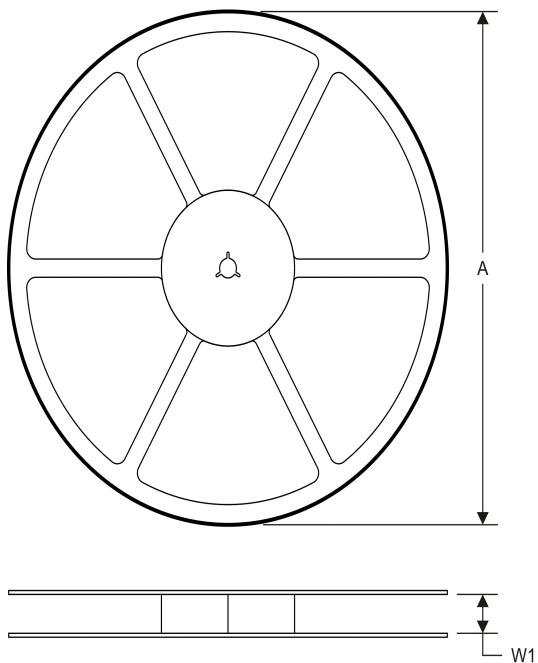
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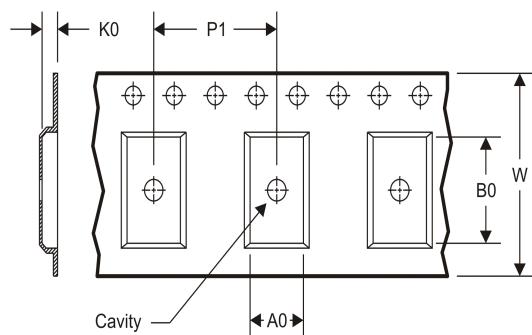
PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS

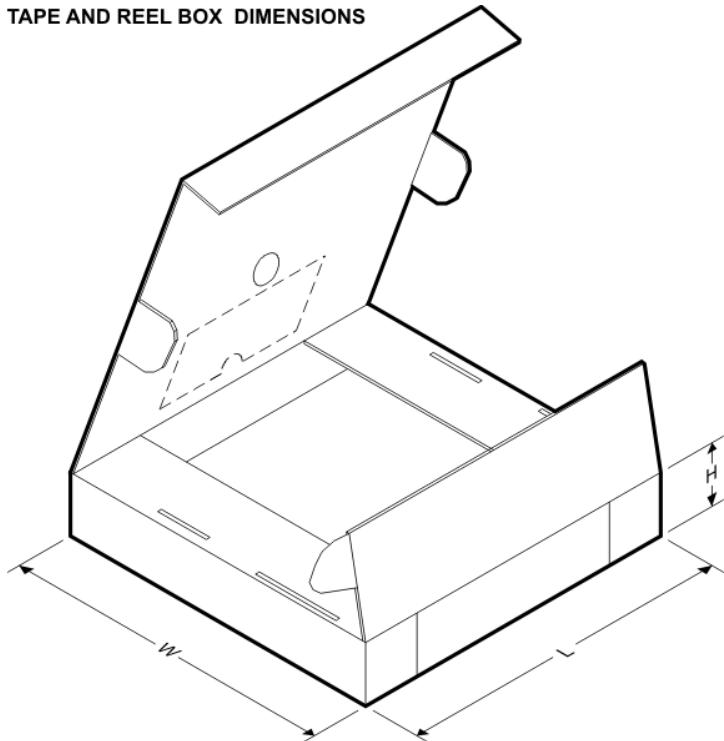


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75LBC776DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

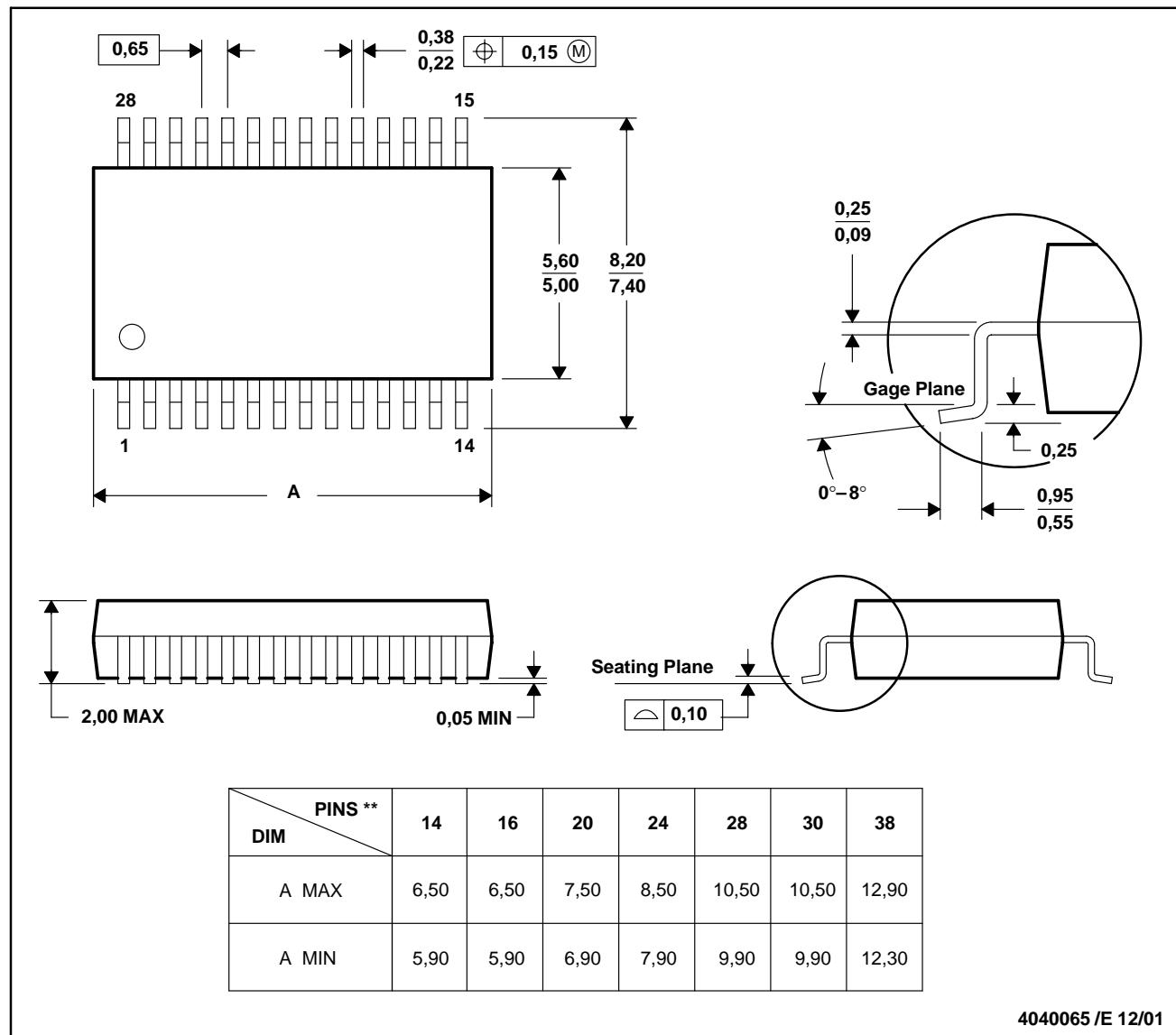
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75LBC776DBR	SSOP	DB	20	2000	367.0	367.0	38.0

MSS002E – JANUARY 1995 – REVISED DECEMBER 2001

DB (R-PDSO-G)**

28 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-150

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No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

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